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PATENT APPLICATION
Docket No. 2522-039
Client No. AW8115US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application for: Si-Youn KIM and Ki-Jae HUR

Filing Date: September 24, 2003 Art unit: 2812

Serial No. 10/670,485 Examiner: Not yet assigned

Title: BOTTOM ELECTRODE OF CAPACITOR OF SEMICONDUCTOR
DEVICE AND METHOD OF FORMING THE SAME

Confirmation No. 7999

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

This Information Disclosure Statement is submitted:

☒ under 37 CFR 1.97 (b); or
(Within three months of filing national application; or date of entry of International application; or before mailing date of first office action on the merits; whichever occurs last)

☒ Applicant(s) submit herewith Form PTO 1449- Information Disclosure Citation together with copies of patents, publications or other information of which applicant(s) are aware, which applicant(s) believe(s) may be material to the examination of this application and for which there may be a duty to disclose in accordance with 37 CFR 1.56.


It is requested that the information disclosed herein be made of record in this application.

Any deficiency or overpayment should be charged or credited to deposit account number 13-1703. A duplicate copy of this sheet is enclosed.

Customer No. 20575

Respectfully submitted,

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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450
Date: September 22, 2004


Adrienne Chocholak



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FORM PTO-1449 (Modified)

U.S. PATENT DOCUMENTS

Exam <u>Init</u>	<u>Ref</u>	Document <u>Number</u>	Issue <u>Date</u>	<u>Name</u>	<u>Class</u>	Sub <u>Class</u>
_____	_____	5,943,582	8/24/1999	Huang, et al.		
_____	_____	US 6,235,639 B1	5/22/2001	Sandhu, et al.		
_____	_____	US 2003/0017677 A1	1/23/2003	Yu, et al.		
_____	_____	US 2003/0121132 A1	7/3/2003	Oh, et al.		

FOREIGN PATENT DOCUMENTS

Exam <u>Init</u>	<u>Ref</u>	Document <u>Number</u>	Publication <u>Date</u>	<u>Country</u>	<u>Name</u>
_____	_____	2002-0070730	9/11/2002	Korea	Choi, et al.

OTHER DOCUMENTS

Exam <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
_____	_____	English language Abstract of Korean Patent Publication No. 2002-0070730.

Examiner: _____

Date Considered: _____